| | Туре | Hits | Search Text | DBs | Time Stamp |
|----|------|------|---|---|-----------------------|
| 1 | BRS | 3508 | trench adj capacitor | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/01/25 14:41 |
| 2 | BRS | 1445 | (first adj polysilicon) and (second adj polysilicon) and (third adj polysilicon) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/01/23 12:32 |
| 3 | BRS | 342 | collar adj oxide | DERWENT; IBM_TDB | 2004/01/23 12:33 |
| 4 | BRS | 571 | node adj dielectric | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/01/23 12:33 |
| 5 | BRS | 0 | buried adj diffusion adj plate | DERWENT; IBM_TDB | 2004/01/23 12:33 |
| 6 | BRS | 2923 | pad adj layer | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/01/23 12:33 |
| 7 | BRS | 0 | <pre>(trench adj capacitor) and ((first adj polysilicon) and (second adj polysilicon) and (third adj polysilicon)) and (collar adj oxide) and (node adj dielectric) and (pad adj layer)</pre> | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/01/23 12:34 |
| 8 | BRS | 121 | (trench adj capacitor) and ((first adj polysilicon) and (second adj polysilicon) and (third adj polysilicon)) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/01/23 12:34 |
| 9 | BRS | 15 | (trench adj capacitor) and ((first adj polysilicon) and (second adj polysilicon) and (third adj polysilicon)) and (node adj dielectric) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/01/23 12:34 |
| 10 | BRS | 0 | (trench adj capacitor) and ((first adj polysilicon) and (second adj polysilicon) and (third adj polysilicon)) and (node adj dielectric) and (pad adj layer) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/01/23 12:35 — |
| 11 | BRS | 16 | (trench adj capacitor) and ((first adj polysilicon) and (second adj polysilicon) and (third adj polysilicon)) and (collar adj oxide) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/01/23 12:35 |
| 12 | BRS | 5 | (trench adj capacitor) and ((first adj polysilicon) and (second adj polysilicon) and (third adj polysilicon)) and (pad adj layer) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 117.42 |

| | Туре | Hits | Search Text | DBs | Time Stamp |
|----|------|------|--|---|---------------------|
| 13 | BRS | 9 | (trench adj capacitor) and ((first adj polysilicon) and (second adj polysilicon) and (third adj polysilicon)) and (collar adj oxide) and (node adj dielectric) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/01/23 12:43 |
| 14 | BRS | 2 | (trench adj capacitor) and ((first adj polysilicon) and (second adj polysilicon) and (third adj polysilicon)) and (collar adj oxide) and (pad adj layer) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/01/23 12:44 |
| 15 | BRS | 0 | "10604287" | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/01/23 13:05 |
| 16 | BRS | 2 | 6472702.pn. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/01/28 13:33 |
| 17 | BRS | 131 | node with ONO | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/01/25 14:41 |
| 18 | BRS | 16 | (trench adj capacitor) and (node with ONO) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/01/25 14:42 |
| 19 | BRS | 32 | photoresist same sacrificial | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/01/25 14:42 |
| 20 | BRS | 0 | (trench adj capacitor) and (photoresist same sacrificial) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/01/25 14:42 |
| 21 | BRS | 2 | capacitor and (photoresist same sacrificial) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/01/25 14:42 |
| 22 | BRS | 2 | 5198386.pn. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/01/28 13:34 |

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